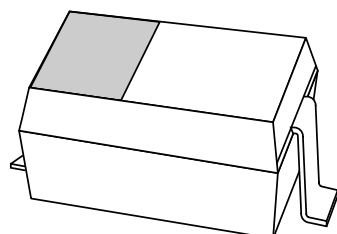


DATA SHEET



BAP63-03 Silicon PIN diode

Product specification
Supersedes data of 2001 Apr 04

2001 May 18

Silicon PIN diode

BAP63-03

FEATURES

- High speed switching for RF signals
- Low diode capacitance
- Low diode forward resistance
- Very low series inductance
- For applications up to 3 GHz.

APPLICATIONS

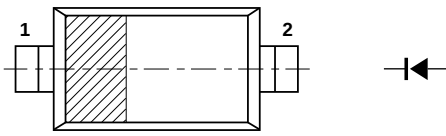
- RF attenuators and switches.

DESCRIPTION

Planar PIN diode in a SOD323 small SMD plastic package.

PINNING

PIN	DESCRIPTION
1	cathode
2	anode



MAM406

Marking code: D2.

Fig.1 Simplified outline (SOD323) and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_R	continuous reverse voltage		–	50	V
I_F	continuous forward current		–	100	mA
P_{tot}	total power dissipation	$T_s \leq 90\text{ }^{\circ}\text{C}$	–	500	mW
T_{stg}	storage temperature		–65	+150	$^{\circ}\text{C}$
T_j	junction temperature		–65	+150	$^{\circ}\text{C}$

Silicon PIN diode

BAP63-03

ELECTRICAL CHARACTERISTICST_j = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V _F	forward voltage	I _F = 50 mA	0.95	1.1	V
I _R	reverse leakage current	V _R = 35 V	–	10	nA
C _d	diode capacitance	V _R = 0; f = 1 MHz	0.4	–	pF
		V _R = 1 V; f = 1 MHz	0.35	–	pF
		V _R = 20 V; f = 1 MHz	0.27	0.32	pF
r _D	diode forward resistance	I _F = 0.5 mA; f = 100 MHz; note 1	2.5	3.5	Ω
		I _F = 1 mA; f = 100 MHz; note 1	1.95	3	Ω
		I _F = 10 mA; f = 100 MHz; note 1	1.17	1.8	Ω
		I _F = 100 mA; f = 100 MHz; note 1	0.9	1.5	Ω
S ₂₁ ²	isolation	V _R = 0; f = 900 MHz	15.4	–	dB
		V _R = 0; f = 1800 MHz	10.1	–	dB
		V _R = 0; f = 2450 MHz	7.8	–	dB
S ₂₁ ²	insertion loss	I _F = 0.5 mA; f = 900 MHz	0.21	–	dB
		I _F = 0.5 mA; f = 1800 MHz	0.28	–	dB
		I _F = 0.5 mA; f = 2450 MHz	0.38	–	dB
S ₂₁ ²	insertion loss	I _F = 1 mA; f = 900 MHz	0.18	–	dB
		I _F = 1 mA; f = 1800 MHz	0.26	–	dB
		I _F = 1 mA; f = 2450 MHz	0.35	–	dB
S ₂₁ ²	insertion loss	I _F = 10 mA; f = 900 MHz	0.13	–	dB
		I _F = 10 mA; f = 1800 MHz	0.20	–	dB
		I _F = 10 mA; f = 2450 MHz	0.30	–	dB
S ₂₁ ²	insertion loss	I _F = 100 mA; f = 900 MHz	0.10	–	dB
		I _F = 100 mA; f = 1800 MHz	0.18	–	dB
		I _F = 100 mA; f = 2450 MHz	0.28	–	dB
τ _L	charge carrier life time	when switched from I _F = 10 mA to I _R = 6 mA; R _L = 100 Ω; measured at I _R = 3 mA	310	–	ns
L _S	series inductance		1.5	–	nH

Note

1. Guaranteed on AQL basis: inspection level S4, AQL 1.0.

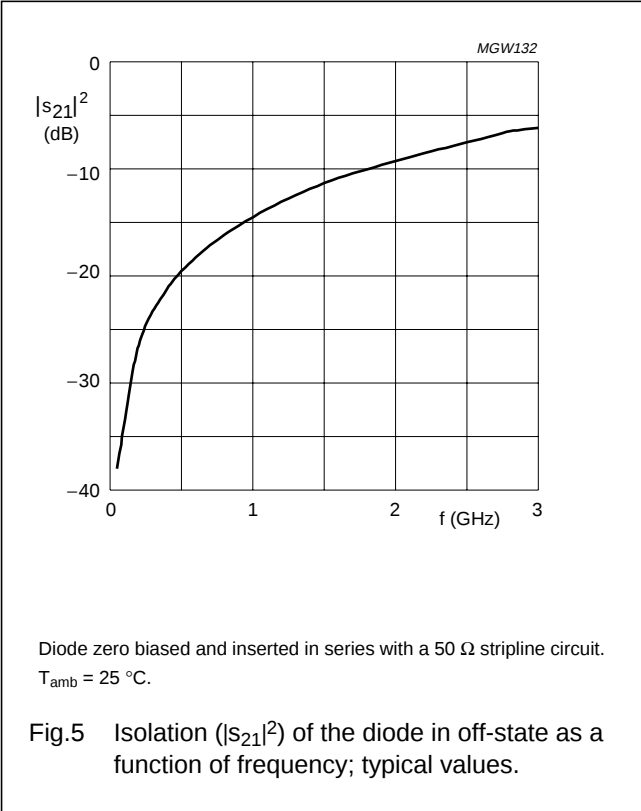
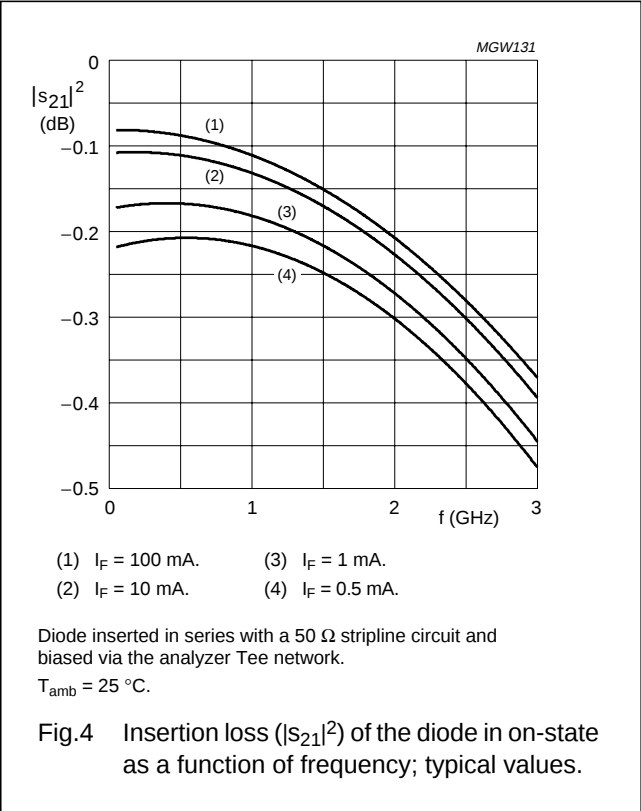
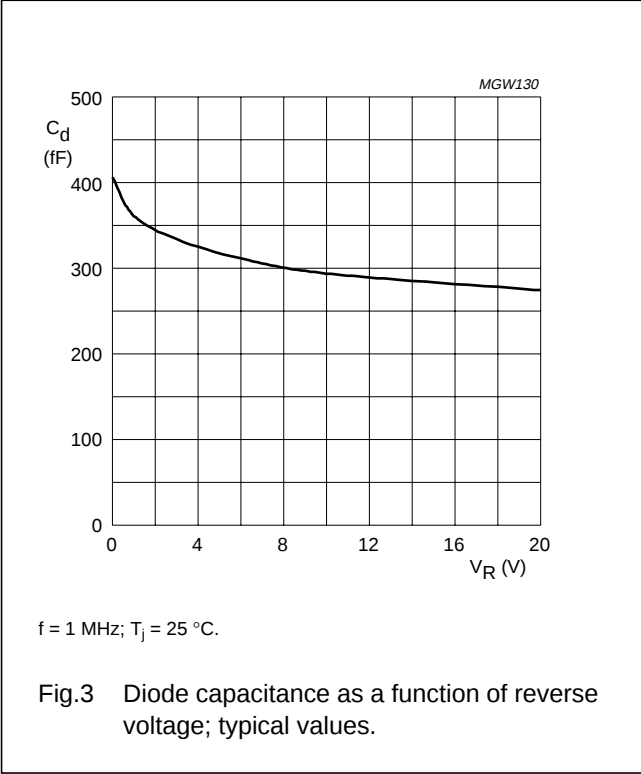
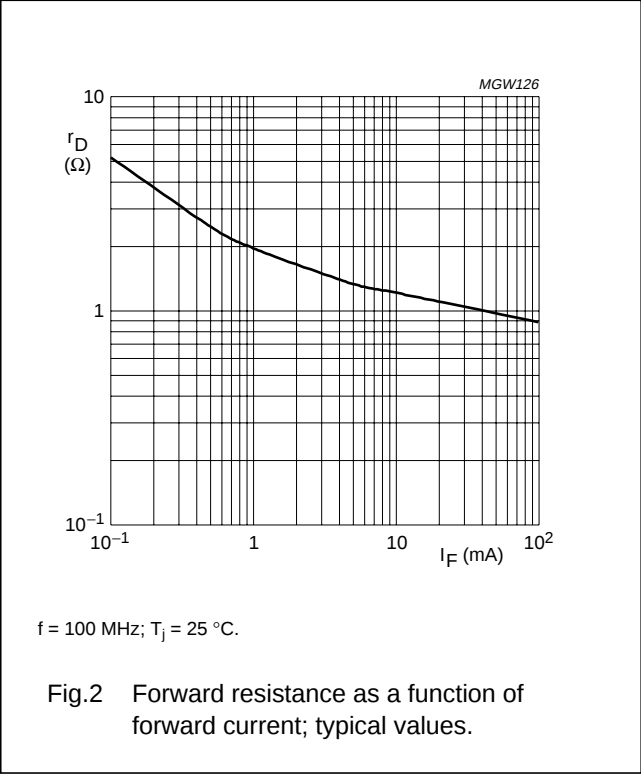
THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
R _{th j-s}	thermal resistance from junction to soldering point	120	K/W

Silicon PIN diode

BAP63-03

GRAPHICAL DATA



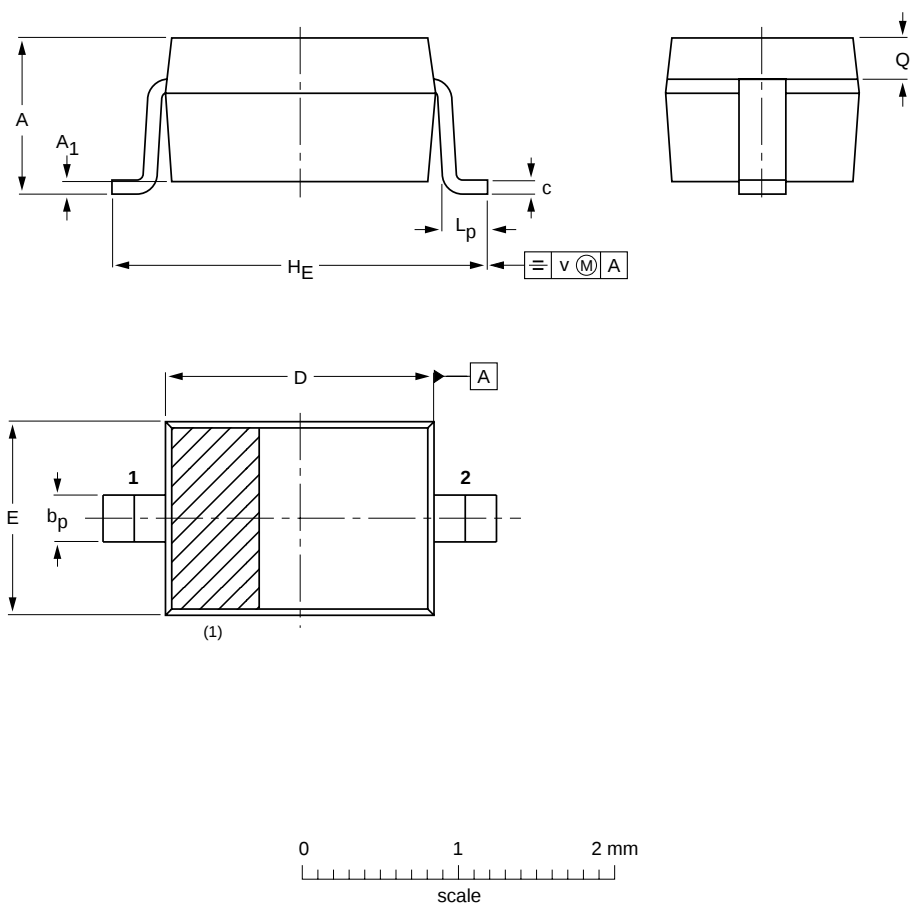
Silicon PIN diode

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PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD323



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁ max.	b _p	c	D	E	H _E	L _p	Q	v
mm	1.1 0.8	+ 0.05 - 0.05	0.40 0.25	0.25 0.10	1.8 1.6	1.35 1.15	2.7 2.3	0.45 0.15	0.25 0.15	0.2

Note

1. The marking bar indicates the cathode.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOD323			SC-76			98-09-14 99-09-13

Silicon PIN diode

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DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITIONS
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Silicon PIN diode

BAP63-03

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Printed in The Netherlands

613512/03/pp8

Date of release: 2001 May 18

Document order number: 9397 750 08262

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